

NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE3401C uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a load switch or in PWM applications.

General Features

• $V_{DS} = -30V, I_{D} = -4.8A$

 $R_{DS(ON)}$ =70m Ω @ V_{GS} =-2.5V

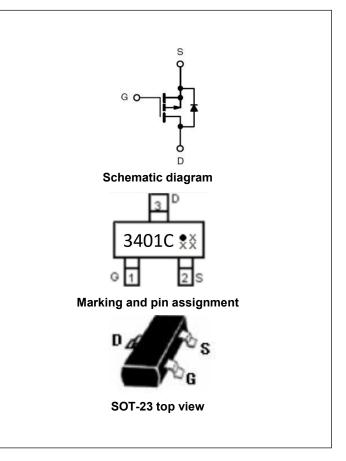
 $R_{DS(ON)}$ =40m Ω @ V_{GS} =-4.5V

 $R_{DS(ON)}$ =33m Ω @ V_{GS} =-10V

- High power and current handing capability
- Lead free product is acquired
- Surface mount package

Application

- Automotive application
- PWM applications
- Load switch
- Power management



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3401C * X	NCE3401C	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25 ℃ unless otherwise noted)

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Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	-30	V
Gate-Source Voltage	Vgs	±12	V
Drain Current-Continuous(Package Limited)	I _D	-4.8	А
Drain Current -Pulsed (Note 1)	I _{DM}	-30	А
Maximum Power Dissipation	P _D	1.4	W
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance,Junction-to-Ambient (Note 2)	ReJA	89	°C/W		



Electrical Characteristics (T_A=25 $^{\circ}$ C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•		•	
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250μA	-30	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V,V _{GS} =0V	-	-	-1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±12V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	-		'			l .
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-0.7	-1	-1.3	V
		V _{GS} =-10V, I _D =-4A	-	33	38	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-3A	-	40	52	mΩ
		V _{GS} =-2.5V, I _D =-1A	-	70	90	mΩ
Forward Transconductance	g FS	V_{DS} =-5 V , I_{D} =-4 A	-	12	-	S
Dynamic Characteristics (Note4)	-		'		1	'
Input Capacitance	C _{lss}	45)()(0)(-	835	-	PF
Output Capacitance	Coss	V _{DS} =-15V,V _{GS} =0V,	-	75	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	56	-	PF
Switching Characteristics (Note 4)	'		•	•	1	<u> </u>
Turn-on Delay Time	t _{d(on)}		-	7	-	nS
Turn-on Rise Time	t _r	V_{DD} =-15 V , I_D =-4 A V_{GS} =-10 V , R_{GEN} =6 Ω	-	3	-	nS
Turn-Off Delay Time	t _{d(off)}		-	30	-	nS
Turn-Off Fall Time	t _f		-	12	-	nS
Total Gate Charge	Qg	151/1 44	-	8.8	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =-15 V , I_{D} =-4 A ,	-	2.1	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =-4.5V	-	2.3	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-4A	-	-	-1.2	V
Diode Forward Current (Note 2)	Is		_	-	-4.8	Α

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics

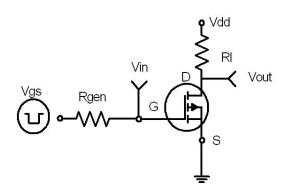


Figure 1:Switching Test Circuit

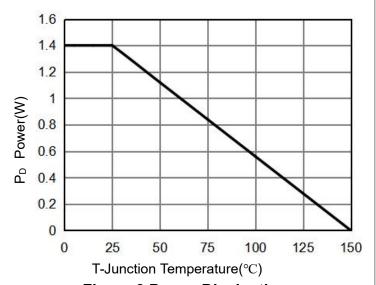


Figure 3 Power Dissipation

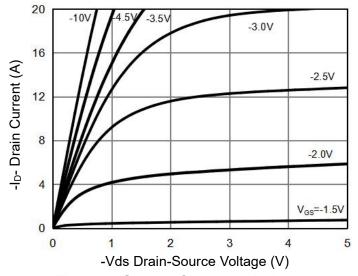


Figure 5 Output Characteristics

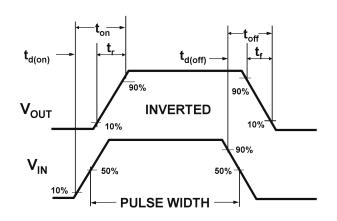


Figure 2:Switching Waveforms

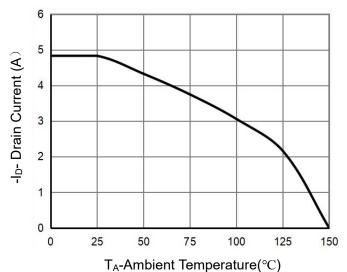


Figure 4 Drain Current

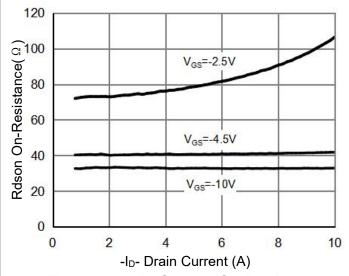


Figure 6 Drain-Source On-Resistance



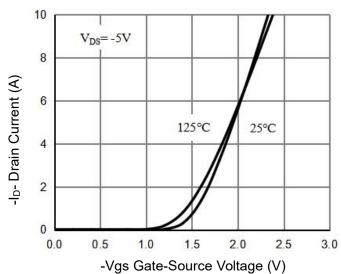
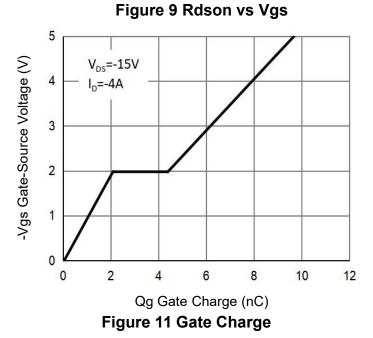


Figure 7 Transfer Characteristics

150
120
90
120
0
2
4
60
-Vgs Gate-Source Voltage (V)



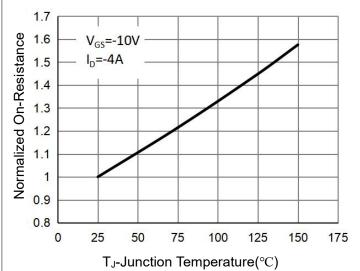


Figure 8 Drain-Source On-Resistance

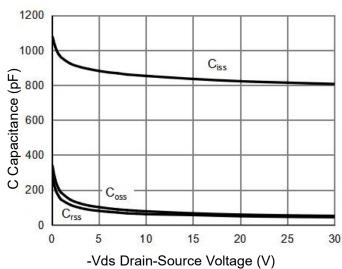


Figure 10 Capacitance vs Vds

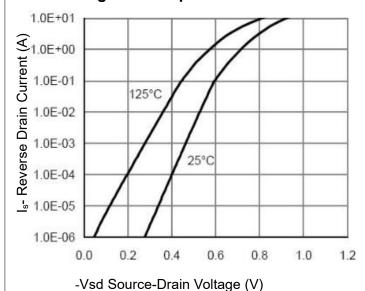


Figure 12 Source- Drain Diode Forward



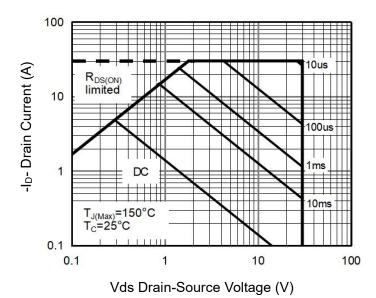


Figure 13 Safe Operation Area

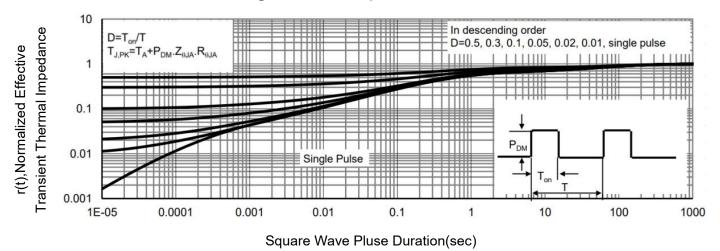
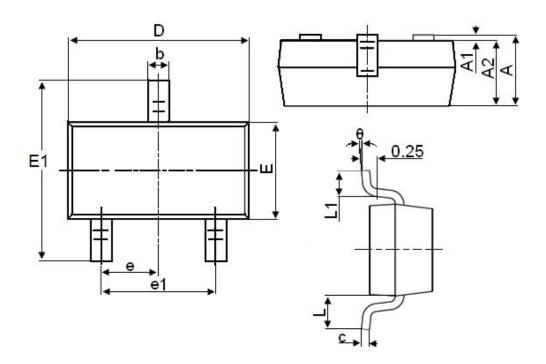


Figure 14 Normalized Maximum Transient Thermal Impedance



SOT-23 Package Information



Cymphol	Dimensions in Millimeters				
Symbol	MIN.	MAX.			
А	0.900	1.150			
A1	0.000	0.100			
A2	0.900	1.050			
b	0.300	0.500			
С	0.080	0.150			
D	2.800	3.000			
Е	1.200	1.400			
E1	2.250	2.550			
е	0.9	0.950TYP			
e1	1.800	2.000			
L	0.9	0.550REF			
L1	0.300	0.500			
θ	0°	8°			

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exac



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